Shahjalal University of Science and Technology (SUST)

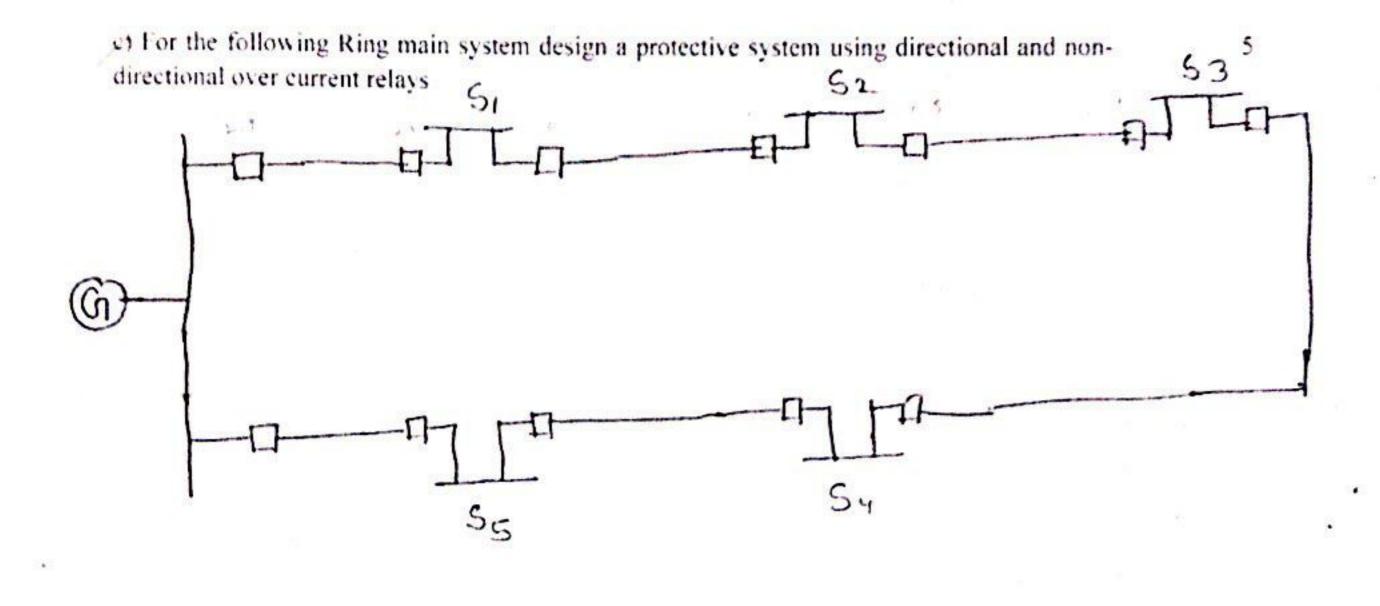
Department of Electrical and Electronic Engineering (EEE)

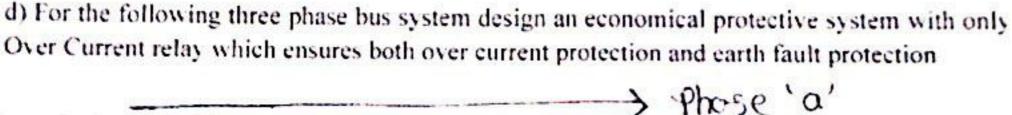
4th Year 2nd Semester Final term Examination- December 2014

ower System Protection

Course Code: EEE- 445

Course Name: Power System Protection			Course Code: EEE- 445	
		Credit: 3.0	Time: 3 Hour	
8.8	(Answer any two questions fr	om Part-A & any two	questions from Part-B)	
		rt- A		
1.	a) What do you mean by switchgear? List the necessity of an isolator.	t some switchgear equ	ipment and hence write down	2+2+3
	b) Mention the salient difference between	Fuse and Circuit Break	ker	5
	e) Why does are is generated when circumethods of are Extinction method? Discu	uit breaker contacts be	gin to separate? What are the	3+1+6
	d) Write down the effect of Restriking vo			3
2.	a) Draw the construction and write dov (SF6) Circuit Breakers	an the operating princ	iple of Sulphur Hexaflouride	3+7
	b) Write the advantages and disadvantage	es of air blast circuit bre	eaker	6
	c) What is Current Chopping? Discuss br	iefly.		5
	d) How many rating circuit breakers do h switching	nave? What are they? W	rite short notes on Resistance	4
3.	a) With schematic discuss the Merz-Price	e circulating current sch	neme for alternator protection	9
	b) Discuss briefly how does torque is pro			7
	c) Discuss the operating principle of proper diagram			9
		PART- B		
4.	a) Write down the operating principle of	f Differential Current R	elay	7
	b)Write down the difference among I	nstantaneous Over Cu	irrent (Define Current) Relay,	4







- g) What is three-zone protection system in a line? Discuss briefly
- 5. A) A 3-phase transformer of 220/11000 line volts is connected in star/delta. The protective transformer on 220V side has a current ratio of 600/5. What should be the CT ratio on 11000 V side? Suppose line current on 220 V side is 600 A.
 - b) As a system engineer if you want to give protection to generator from Phase to ground fault and Phase to Phase fault then which protection scheme do you employ? Describe how does your scheme will give protection against above fault?

10

- c) Discuss the operation of Buchholz relay with detail figure.
- a) How Combined Leakage and Overload Protection can be given to a transformer?
 b) What is voltage surge? What are the internal causes of over voltage? What are the harmful effects of Lightening? What are the protective measures against lightening?
 c) Explain how generator behaves during LOSS-OF-SYNCHRONISM, OVERSPEED and
 - d) How does a motor can be protected from overloading?

Loss of excitation.

BEST of Luck for Your Future

Shahjalal University of Science & Technology

Department of Electrical & Electronic Engineering

4th year 2nd Semester Final Examination - December 2014

Course No: EEE 465

Course Title: Optoelectronics Credits: 3.0 Full Marks: 100 Time: 3 Hours

[Answer any four questions taking two from each group]

Group A

Q1	(a)	Define direct and indirect band gap materials with necessary figures.	0
	(b)	 A 0.46μm thick sample of GaAs is illuminated with monochromatic light of hv=2Ev. The absorption coefficient α is 5X10⁴cm⁻¹. The power incident on the sample is 10mW. (a) Find the total energy absorbed per second (J/s) by the sample. (b) Find the rate of excess thermal energy given up by the electrons to the lattice before recombination (J/s). (c) Find the number of photons per second given off from recombination events, assuming perfect quantum efficiency. 	9
	(c)	Find the E-k relationship for a free electron and relate it to the electron mass.	7
	(d)	Explain in brief how white light is produced by LED.	
02	(a)	Derive the Berr-Lambert law in case of optial absorption. Explain its significance.	7
Q2	(a) (b)	Describe some applications of ontial absorption.	
	(c)	Define minority carrier life time. Derive a general expression that describes the time evolution of the excess minority carrier concentration.	,
	(d)	Briefly describe the principle of operation of an acousto-optic Modulator.	6
1212		Write few distinguishing characteristics of LED display and LCD display.	5
Q3	(a)	Write few distinguishing characteristics of DDB display and distinguishing characteristics of DDB display and the with with proper alloy composition the energy bands of semiconductor changes-explain with	8
	(b)	specific example and diagram.	6
	(c)	titil device structure explain how LED WORKS.	6
	(d)	Given that the width of the relative light intensity versus photon energy spectrum of an LED is typically around $\sim k_B T$, what should be the line width $\Delta \lambda_{1/2}$ in the output spectrum in terms of wavelength?	

Group B

Q4		John Middle Control of the Control o	
	(b)	Explain the principle of operation of holography	7
	(c)	What are the conditions required to fulfill to get lasing action?	2
	(d)	With necessary diagram and figure explain the principle of operation of semiconductor LASER diode.	6
	(e)	Explain buried heterostructure laser diode.	4
Q5	(a)	Write short notes on quantum efficiency and responsivity of a photodiode.	6
	(b)	Define photoconductivity. Prove that photoconductive gain, $G = \frac{\tau}{t_e} (1 + \frac{\mu_h}{\mu_e})$, where $\tau =$	8
		mean recombination time, t_e = electron's transit time, μ_h = hole drift mobility, μ_e = electron drift mobility.	
	(c)	Describe the operating principle of p-i-n photodiode.	33
	(d)	A Si PIN photodiode has an active tiefer and it is a series of the series and active tiefer and the series are active tiefer and the	6
	(4)	A Si PIN photodiode has an active light receiving area of diameter 0.4 mm. When radiation of wavelength 700 nm (red light) and intensity 0.1 mWcm ⁻² is incident it generates a photocurrent of 56.6 nA. What would be the responsivity and QE of the photodiode at 700 nm?	5
Q6	(a)	An APD with a multiplication factor of 20 operates at a wavelength of 1.5 μ m. Calculate the quantum efficiency and the output photocurrent from the device if its responsivity at this wavelength is $0.6AW^{-1}$ and 10^{10} photons of wavelength 1.5 μ m are incident upon it per second.	6
	(b)	With block diagram briefly explain the operation of FSK of optical signal.	4
	(c)	Distinguish between homodyne and intradyne detection of optical modulated signal.	4
	(d)	How does Mach-Zehnder modulator work?	5
	(e)	A solar cell under an illumination of $100 Wm^{-2}$ has a short circuit current I_{sc} of 50mA and an open circuit output voltage V_{oc} of 0.55 V. What is the short circuit current and open circuit voltage if the light intensity is halved?	6

Shahjalal University of Science and Technology Department of Electrical and Electronic Engineering Final Examination June-Dec. 2014

Course Code: EEE 491

Course Title: Biomedical Instrumentation

Total Marks: 100

Part A

Answer any	two o	the	following	questions.
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1.	a)	Define: i) Biometrics ii) Man-instrument system	4
	b)	What is a Transducer? Explain briefly with their biomedical application of the following transducer. i) Inductive transducer ii) Piezoelectric transducer iii) Capacitive transducer.	6
	c)	Describe the formation of resting and action potentials in a typical cell.	7
	d)	Briefly describe the cardiovascular circulation with a neat block diagram.	8
2.	a)	'Any portion of heart can act as pacemaker'-explain. Describe different modes of pacemaker operation.	8
	b)	Draw a typical ECG cycle and define its different waves.	5
	c)	What changes occur in ECG due to abnormality and why? Describe different types of cardiac abnormality detected by ECG.	12
3.	a)	Define bradycardia and tachycardia. Derive the minimum sampling frequency required for the sampling of ECG to calculate IHR with an error of ±1 bpm.	2+6
	b)	With neat diagram describe the systole and diastole showing the relation among different cardiac activities. Also show the relationship of heart sounds to function of the cardiovascular system.	8
	c)	Define ECG lead. With neat diagrams, describe the formation of different ECG leads.	1+8

Part B

Answer any two of the following questions

4.	a)	Write the basic physics of MRI. Describe the instrumentation and image formation in MRI.	10
	b)	Describe blood pressure measuring techniques. Describe the operation of a BP detector circuit.	12
	c)	Write the uses of EEG	3
5.	~a)	Describe the scanning modes of medical ultrasongraphy.	8
	(b)	With neat diagrams describe the operation of a colorimeter.	12
	c)	Describe ultrasonic blood flowmeters.	5
6.	<u>a</u>)	Define different tests of blood normally conducted.	11
	b)	Describe the use of impedance plethysmography in determining thorax impedance and stroke volume.	14

Department of Electrical and Electronic Engineering Shahjalal University of Science and Technology

Course Code: EEE 485

Course Title: Cellular Mobile and Satellite Communication 4th year 2nd semester final examination, 2014, Session-2010-11

Total Marks: 100 Duration: 3hours

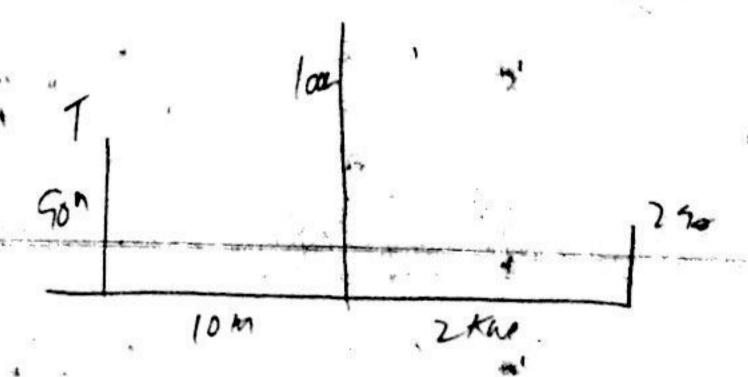
Part A.

(Answer any two questions)

Q1. a) Show the various upgrade paths for 2G technologies.

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- b) Provide the timing diagram that illustrates how a call initiated by a mobile is established.
- c) Discuss about handoff strategies and practical handoff considerations.
- d) An urban area has a population of two million residents. Three competing trunked mobile networks (Systems A, B and C) provide cellular service in this area. System A has 394 cells with 19 channels each, system B has 98 cells with 57 channels each and system C has 49 cells each with 100 channels. Find the number of users that can be supported at 2% blocking if each user averages two calls per hour at average call duration of five minutes. Assuming that all three trunked systems are operated at maximum capacity, compute the percentage market penetration of each cellular provider.
- Q2. a) What do you know about cell splitting and sectoring? Also explain how coverage and capacity is improved in cellular systems using these techniques.
- b) Find the phase difference and time delay between two signals using ground reflection model.6
- c) Given the following geometry, determine (i) the loss due to knife edge diffraction and (ii) the height of the obstacle required to induce 6dB diffraction loss. Assume f=900MHz.



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d) With'h neat figs	ure explain the basic subsystems of GSM architectu	24	
O3. al Define mar	n and the busic subsystems of GSM architectu	ire	
to o	in excess delay, rms delay spread and excess delay	spread.	ŧ
(i) Compute rms d	elay spread for the following power delay profile.	•	(
	r) ods ods		
6	· 1 , 1	, n	
71			
	o i Lus		
(ii) If BPSK mode channel without ne	ulation is used, what is the maximum bit rate the	at can be sent through	the
c) Discuss about co	herence bandwidth and coherence time.		
	e different types of fading effects due to multipath	time delay spread.	8

Part B

(Answer any two questions)

O4 5) What da		•	4		
Q4. a) What do you know about DS-CDMA? Also write about reverse link DS-CDMA.	forward	link	DS-	CDMA	and
		370			5
b) Generate four bit Walsh codes.				•	5
c) Give information about forward pilot channel, forward sync cha and forward traffic channel and reverse access channel.	nnel, for	ward	pagi	ing cha	nnel
d) Discuss about DS spectrum spreading and dispreading technique.		٠		5	5
Q5. a) Define (i) True anomaly (ii) Eccentric anomaly (iii) Elevative (v) Nadir angle. Draw necessary diagrams.	ion angle	(iv)	Azi	muth a	ngle
(1) Hadir aligic. Draw necessary diagrams.		10 10	•		10

b) Provide the block diagram that depicts satellite communication system and interfacing terrestrial entities.	with
refrestrat entities.	5
c) Write down Kepler's laws.	5
d) What do you know about geostationary satellite? Give only five important information.	5
Q6. a) Give important information about MOLNYA and TUNDRA orbits.	6
b) What do you know about station keeping box?	5
c) Differentiate between CDMA and FDMA.	5
d) What do you know about Effective Isotropic radiated power and power flux density?	5
e) Discuss about the satellite communications links. Give specifications for 'C, 'X', 'Ka' 'Ku' band.	and 4

